

V_R	650V
I_F	8A
Q_C	13nC

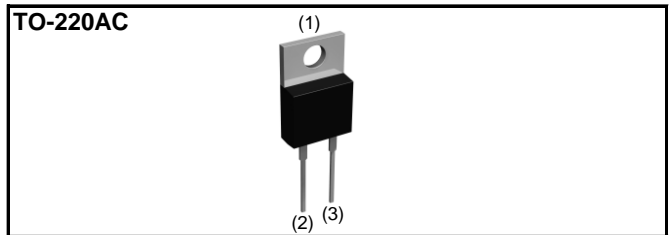
●Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

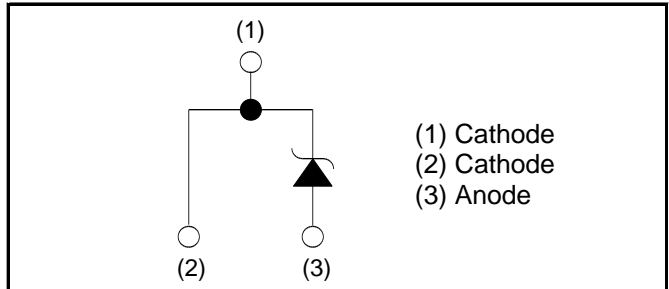
●Construction

Silicon carbide epitaxial planer schottky diode

●AEC-Q101 Qualified



●Inner circuit



●Packaging specifications

Type	Packaging	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	50
	Taping code	C
	Marking	SCS208AG

●Absolute maximum ratings ($T_j = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Reverse voltage (repetitive peak)	V_{RM}	650	V
Reverse voltage (DC)	V_R	650	V
Continuous forward current	I_F	8 ^{*1}	A
Surge no repetitive forward current	I_{FSM}	31 ^{*2}	A
		118 ^{*3}	A
		25 ^{*4}	A
Repetitive peak forward current	I_{FRM}	35 ^{*5}	A
Total power dissipation	P_D	68 ^{*6}	W
Junction temperature	T_j	175	$^\circ\text{C}$
Range of storage temperature	T_{stg}	-55 to +175	$^\circ\text{C}$

*1 $T_c=139^\circ\text{C}$ *2 $PW=8.3\text{ms}$ sinusoidal, $T_j=25^\circ\text{C}$ *3 $PW=10\mu\text{s}$ square, $T_j=25^\circ\text{C}$

*4 $PW=8.3\text{ms}$ sinusoidal, $T_j=150^\circ\text{C}$ *5 $T_c=100^\circ\text{C}$, $T_j=150^\circ\text{C}$, Duty cycle=10% *6 $T_c=25^\circ\text{C}$

●Electrical characteristics (T_j = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
DC blocking voltage	V _{DC}	I _R =0.16mA	600	-	-	V
Forward voltage	V _F	I _F =8A, T _j =25°C	-	1.35	1.55	V
		I _F =8A, T _j =150°C	-	1.55	-	V
		I _F =8A, T _j =175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V, T _j =25°C	-	1.6	160	μA
		V _R =600V, T _j =150°C	-	24	-	μA
		V _R =600V, T _j =175°C	-	56	-	μA
Total capacitance	C	V _R =1V, f=1MHz	-	291	-	pF
		V _R =600V, f=1MHz	-	30	-	pF
Total capacitive charge	Q _C	V _R =400V, di/dt=350A/μs	-	13	-	nC
Switching time	t _c	V _R =400V, di/dt=350A/μs	-	13	-	ns

●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Thermal resistance	R _{th(j-c)}	-	-	1.9	2.2	°C/W

●Electrical characteristic curves

Fig.1 $V_F - I_F$ Characteristics

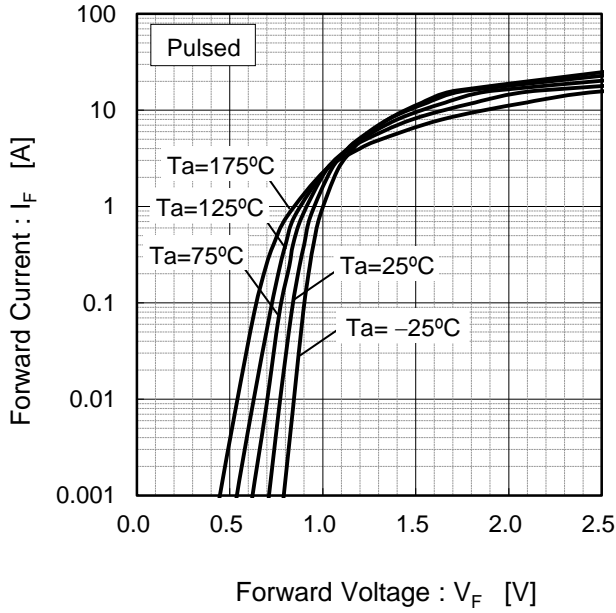


Fig.2 $V_F - I_F$ Characteristics

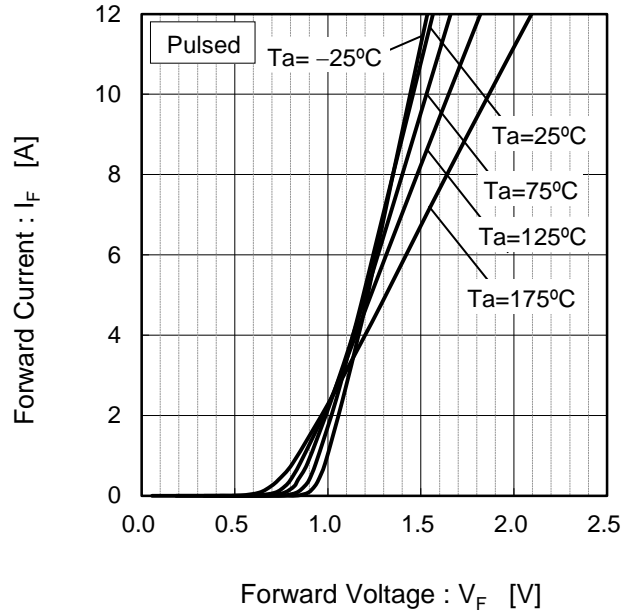


Fig.3 $V_R - I_R$ Characteristics

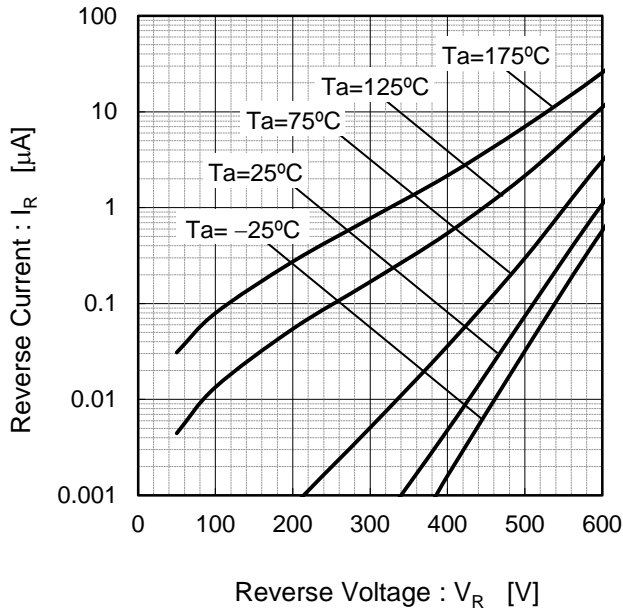
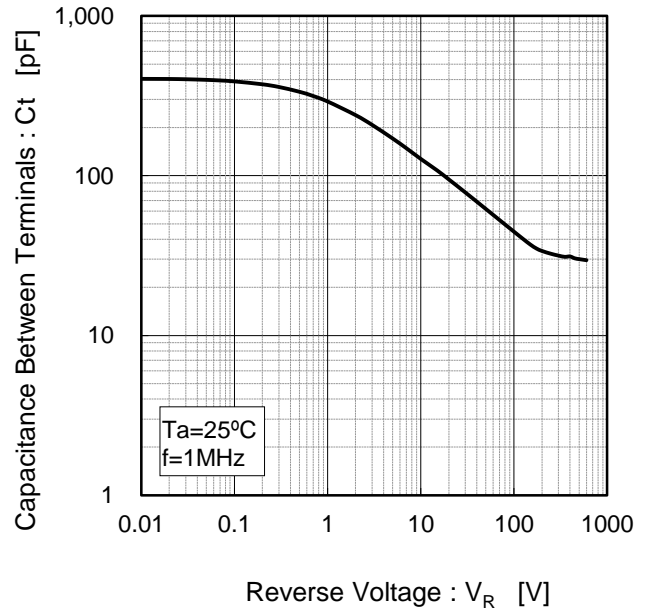


Fig.4 $V_R - C_t$ Characteristics



●Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

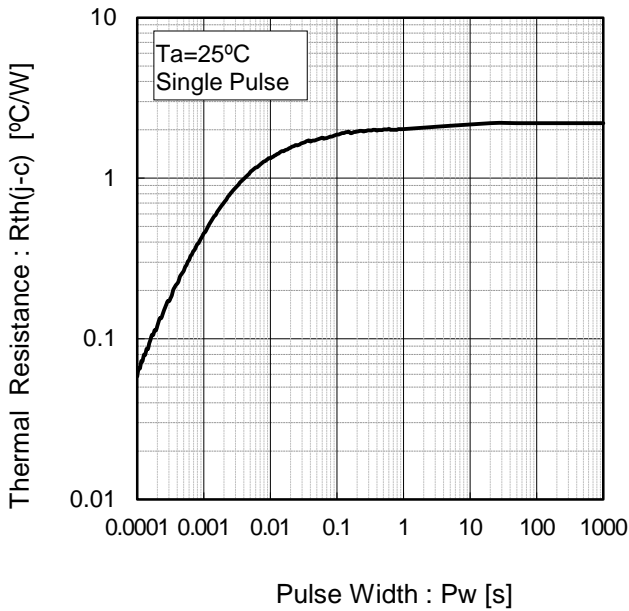


Fig.6 Power Dissipation

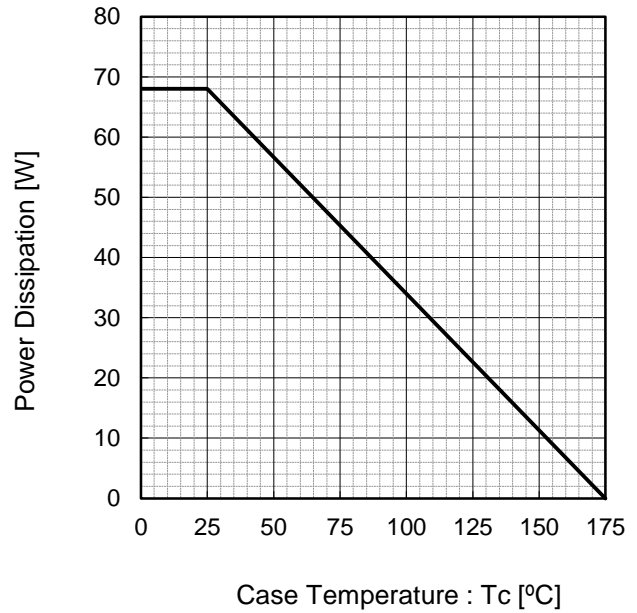


Fig.7 I_p - T_c Derating Curve

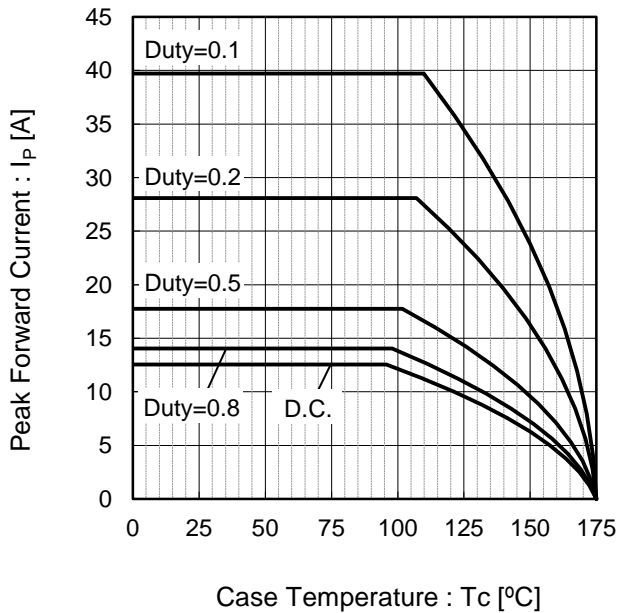
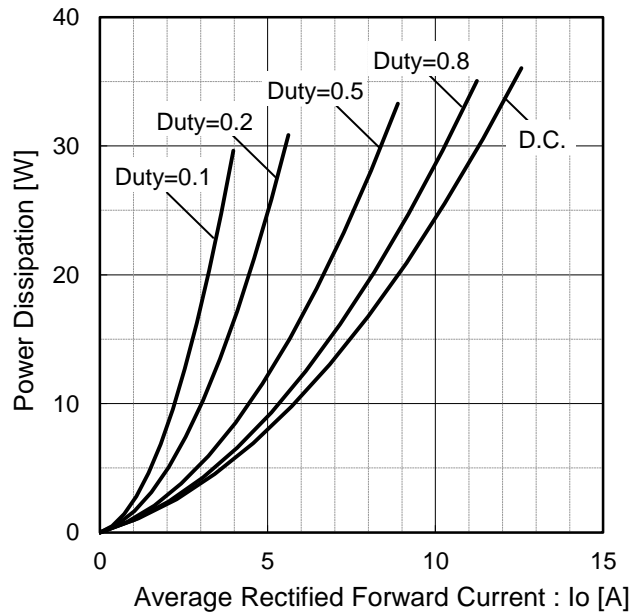


Fig.8 I_o - P_f Characteristics



●Dimensions (Unit : mm)

TO-220AC

